
Average gate power (6 (er))13 dissipation125)

$P_{G(AV)}$

0.5

W

FIG.1: Maximum power dissipation versus RMS on-state current

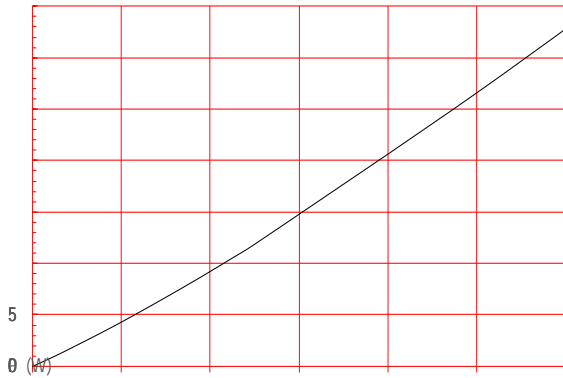
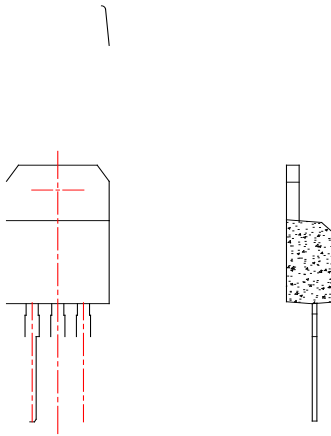


FIG.2: RMS on-state current versus case temperature

PACKAGE MECHANICAL DATA



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